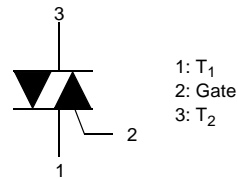
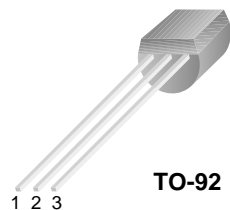


# FKN1N60SA

## TRIAC (Silicon Bidirectional Thyristor)

### Application Explanation

- Switching mode power supply, light dimmer, electric flasher unit, hair drier
- TV sets, stereo, refrigerator, washing machine
- Electric blanket, solenoid driver, small motor control
- Photo copier, electric tool



### Absolute Maximum Ratings T<sub>a</sub> = 25°C unless otherwise noted

Symbol	Parameter	Value	Rating	Units	
V <sub>DRM</sub> V <sub>RRM</sub>	Peak Repetitive Off-State Voltage	Sine Wave 50 to 60Hz, Gate Open	600	V	
I <sub>T (RMS)</sub>	RMS On-State Current	Commercial frequency, sine full wave 360° conduction, T <sub>c</sub> = 70 °C	1.0	A	
I <sub>TSM</sub>	Surge On-State Current	Sinewave 1 full cycle, peak value, non-repetitive	50Hz	9	A
			60Hz	10	A
I <sup>2</sup> t	I <sup>2</sup> t for Fusing	Value corresponding to 1 cycle of halfwave, surge on-state current, t <sub>p</sub> =8.4ms	0.41	A <sup>2</sup> s	
P <sub>GM</sub>	Peak Gate Power Dissipation		5	W	
P <sub>G (AV)</sub>	Average Gate Power Dissipation		0.1	W	
V <sub>GM</sub>	Peak Gate Voltage		5	V	
I <sub>GM</sub>	Peak Gate Current		1	A	
T <sub>J</sub>	Junction Temperature		- 40 ~ 125	°C	
T <sub>STG</sub>	Storage Temperature		- 40 ~ 125	°C	

### Thermal Characteristics

Symbol	Parameter	Value	Units
R <sub>θJC</sub>	Thermal Resistance, Junction to Case <sup>(note1)</sup>	40	°C/W
R <sub>θJA</sub>	Thermal Resistance, Junction to Ambient <sup>(note2)</sup>	160	°C/W

Note1: Infinite cooling condition.

Note2: JE5D51-10 ( Test Borad: FR4 3.0"×4.5"×0.062", Minimum land pad)

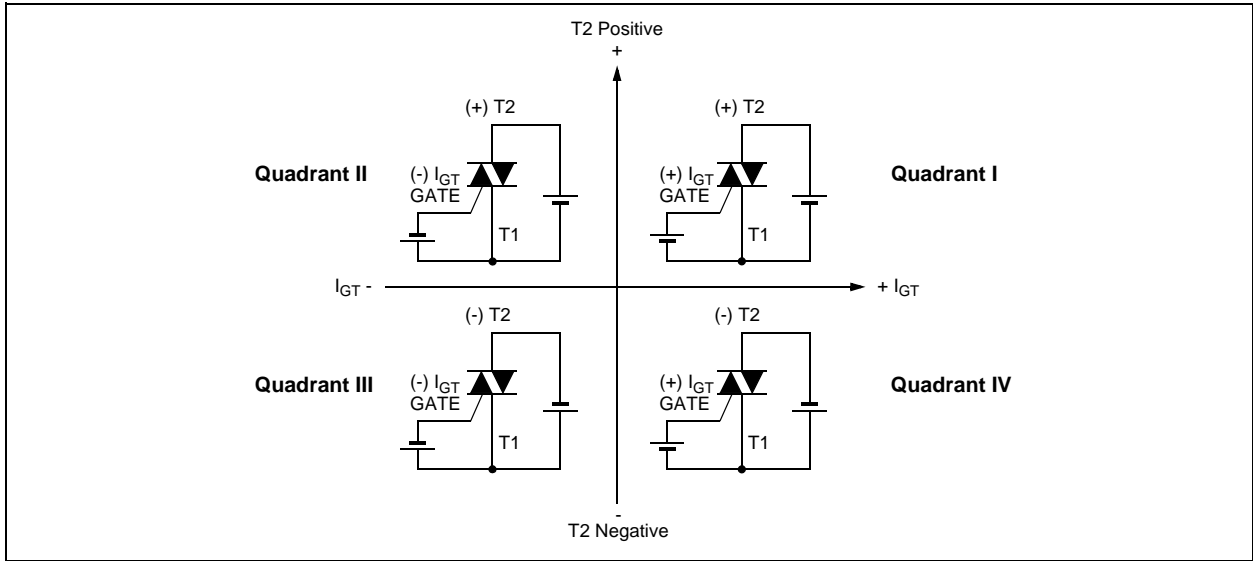
**Electrical Characteristics**  $T_C = 25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units	
$I_{DRM}$ $I_{RRM}$	Repetitive Peak Off-State Current	$V_{DRM}/V_{RRM}$ applied	-	-	100	$\mu\text{A}$	
$V_{TM}$	On-State Voltage	$T_C=25^\circ\text{C}$ , $I_{TM}=1.12\text{A}$ Instantaneous measurement	-	-	1.8	V	
$V_{GT}$	Gate Trigger Voltage	$V_D=12\text{V}$ , $R_L=100\Omega$	T2(+), Gate (+)	-	-	2.0	V
			T2(+), Gate (-)	-	-	2.0	V
			T2(-), Gate (-)	-	-	2.0	V
$I_{GT}$	Gate Trigger Current	$V_D=12\text{V}$ , $R_L=100\Omega$	T2(+), Gate (+)	-	-	5	mA
			T2(+), Gate (-)	-	-	5	mA
			T2(-), Gate (-)	-	-	5	mA
$V_{GD}$	Gate Non-Trigger Voltage	$T_J=125^\circ\text{C}$ , $V_D=1/2V_{DRM}$	0.2	-	-	V	
$I_H$	Holding Current (I, II, III)	$V_D = 12\text{V}$ , $I_{TM} = 200\text{mA}$	-	-	15	mA	
$I_L$	Latching Current	$V_D = 12\text{V}$ , $I_G = 10\text{mA}$	I, III	-	-	15	mA
			II	-	-	20	mA
$dv/dt(s)$	Critical Rate of Rise of Off-State Voltage	$V_{DRM} = 63\%$ Rated, $T_J = 125^\circ\text{C}$ , Exponential Rise	20	-	-	$\text{V}/\mu\text{s}$	
$dv/dt(c)$	Critical-Rate of Rise of Off-State Commutating Voltage ( $di/dt=-0.7\text{A}/\mu\text{s}$ )		3.0	-	-	$\text{V}/\mu\text{s}$	

**Commutation  $dv/dt$  test**

Device	Test Condition	Commutating voltage and current waveforms (inductive load)
FKN1N60SA	1. Junction Temperature $T_J=125^\circ\text{C}$ 2. Rate of decay of on-state commutating current $(di/dt)_C$ 3. Peak off-state voltage $V_D = 300\text{V}$	

### Quadrant Definitions for a Triac

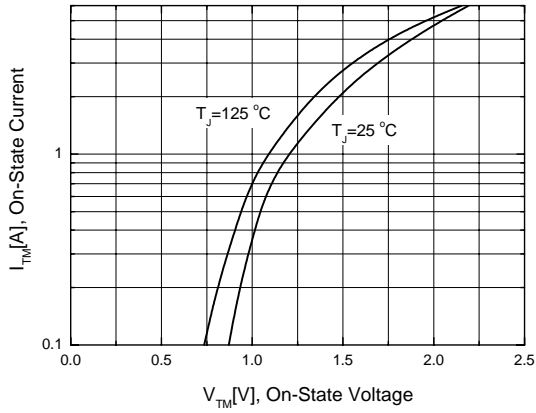


### Package Marking and Ordering Information

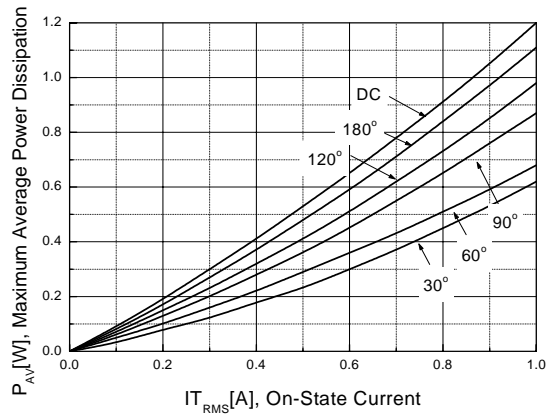
Device Marking	Device	Package	Packing	Tape Width	Quantity
K1N60SA	FKN1N60SA	TO-92	Bulk	--	--

## Typical Performance Characteristics

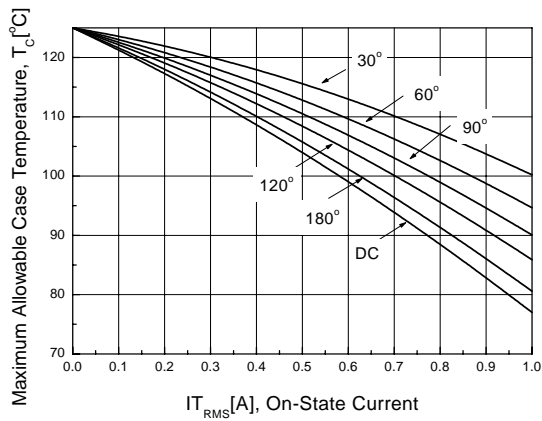
**Figure 1. On-State Characteristics**



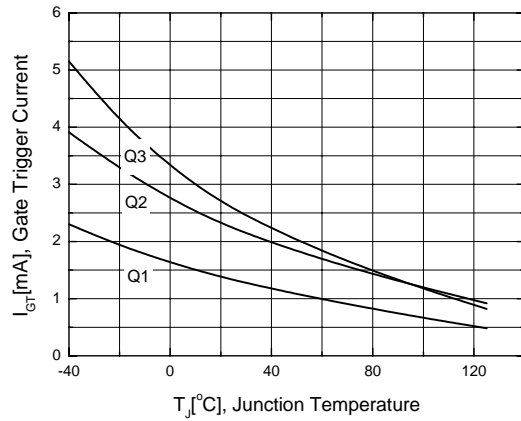
**Figure 2. Power Dissipation**



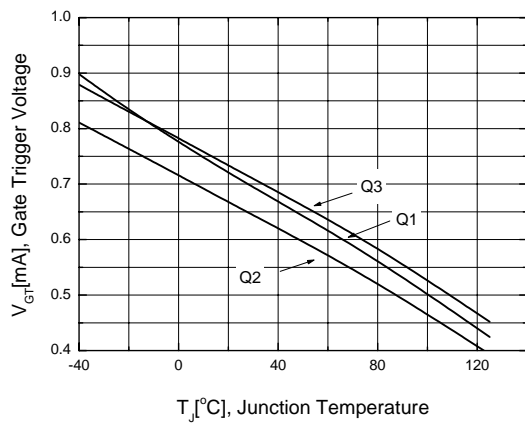
**Figure 3. RMS Current Rating**



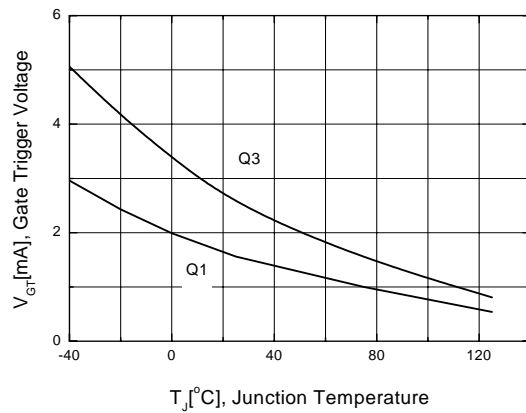
**Figure 4. Typical Gate Trigger Current vs Junction Temperature**



**Figure 5. Typical Gate Voltage vs Junction Temperature**

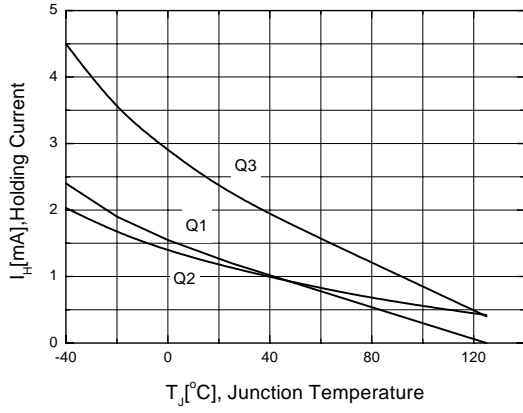


**Figure 6. Typical Latching Current vs Junction Temperature**

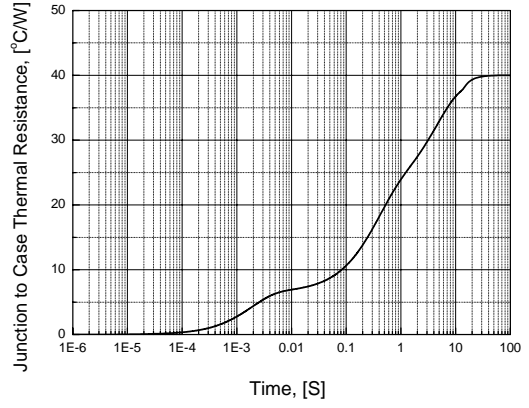


**Typical Performance Characteristics** (Continued)

**Figure7. Typical Holding Current vs Junction Temperature**

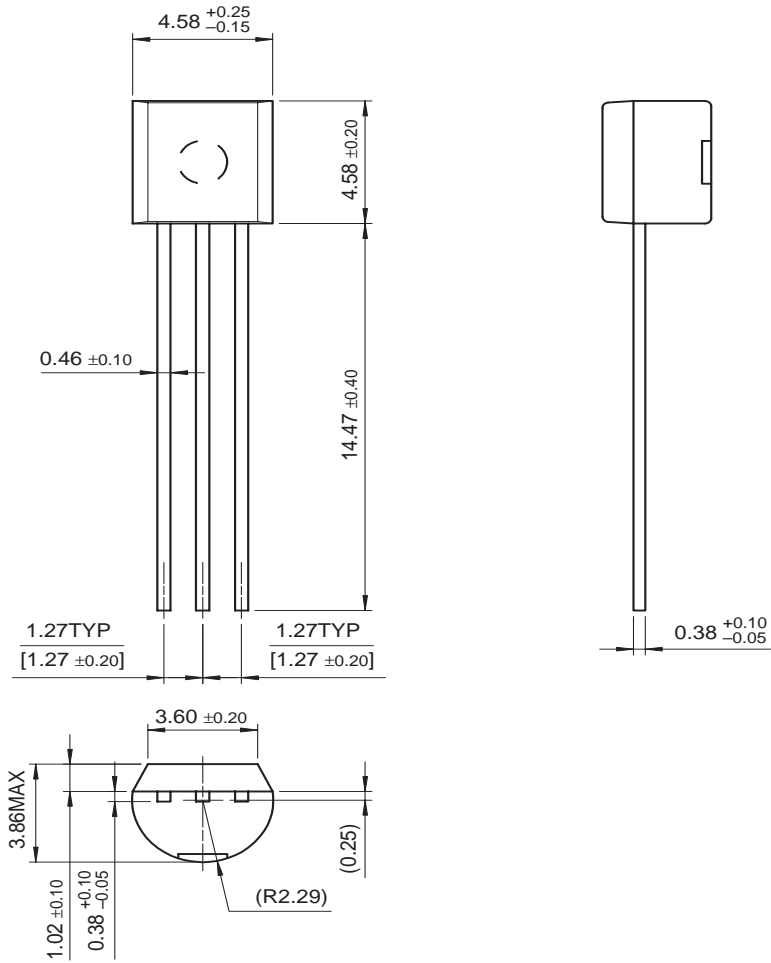


**Figure8. Junction to Case Thermal Resistance**



# Package Dimension

## TO-92



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Build it Now™	HiSeC™	OPTOPLANAR™	Stealth™	Wire™
CoolFET™	I <sup>2</sup> C™	PACMAN™	SuperFET™	
CROSSVOLT™	i-Lo™	POPT™	SuperSOT™-3	
DOMETM	ImpliedDisconnect™	Power247™	SuperSOT™-6	
EcoSPARK™	IntelliMAX™	PowerEdge™	SuperSOT™-8	
E <sup>2</sup> C MOS™	ISOPLANAR™	PowerSaver™	SyncFET™	
EnSigna™	LittleFET™	PowerTrench®	TCM™	
FACT™	MICROCOUPLER™	QFET®	TinyBoost™	
FAST®	MicroFET™	QS™	TinyBuck™	
FASTr™	MicroPak™	QT Optoelectronics™	TinyPWM™	
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